Accurate Prediction Method of Breakdown Voltage in Air at Atmospheric Pressure

Nam-Kyung Kim*, Se-Hee Lee*, G. E. Georghiou**, Dong-Wook Kim* and Dong-Hun Kim†

Abstract – To predict accurately the breakdown voltage in air at atmospheric pressure, a fully coupled finite element analysis combining the hydrodynamic diffusion-drift equations with Poisson’s equation is proposed in the current paper. As three kinds of charged transport particles are non-linearly coupled with spatial electric fields, the equations should be solved by an iterative numerical scheme, in which secondary effects, such as photoemission and photoionization, are considered. The proposed method has been successfully applied to evaluate the breakdown voltage in circular parallel-plane electrodes. Its validity has been proved through the comparison of the predicted and experimental results. The effects of numerical conditions of the initial charge, photoemission, and background ionization on the discharge phenomena are quantitatively assessed through Taguchi’s design of experiment method.

Keywords: Electric breakdown, Electron emission, Finite element method, Gas discharges

1. Introduction

In the development of electric systems, such as high-voltage apparatuses and micro-electromechanical devices, the breakdown voltage is likely to become a critical issue in achieving robustness of the system designed. Breakdown voltage is usually estimated from empirical data or maximum electric field values calculated by electromagnetic analysis tools. These approaches can only give engineers a global trend of the breakdown voltage in a system. However, to obtain in-depth knowledge of the breakdown, designers need to determine the local characteristics, such as discharge evolution, discharge path, continuous discharge pattern, densities of ions and electrons, etc.

In a quest to explore discharge phenomena, the finite difference method or finite element method (FEM), coupled with the method of characteristics or flux corrected transport method, has been used to date [1-8]. The governing equations for the discharge analysis are generally composed of two kinds of differential equations: the first-order charge transport equation and the second-order electric field equation. The convergence of numerical solutions is strongly dependent on the convective term in the charge transport equation. In such convective-dominated transport problems, instabilities may occur in numerical solutions. These instabilities may be noted as oscillations and exhibit divergence in field solutions. Instabilities can be easily observed in front of the moving charges where steep field gradients appear. To avoid these problems, in the current study, the cell Peclet number is carefully controlled by generating fine meshes around the discharge column between electrodes.

To simulate the breakdown situation more accurately, secondary effects, such as the photoemission, background ionization, and photoionization, should be considered during the discharge process. In the current paper, the mechanism of photoemission and background ionization is embodied in the boundary conditions. The fully coupled finite element model is successfully applied to the prediction of the breakdown voltage and to the analysis of discharge phenomena in circular parallel-plane electrodes. Whereas the effects of the initial charge distribution, photoemission, and background ionization on the discharge phenomena were qualitatively discussed in [1], they are quantitatively assessed in this paper through Taguchi’s design of experiment (DOE) method.

The proposed numerical setup is implemented using the COMSOL Multiphysics software and MATLAB programming environment, with the two packages constantly communicating with each other and exchanging information required for discharge simulation.

2. Fully Coupled Hydrodynamic Diffusion-Drift Models for Discharge Analysis in Air

To analyze the discharge phenomena in air, the fully coupled hydrodynamic diffusion-drift models are
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The unknown variables of electron density ($N_e$), positive ion density ($N_p$), negative ion density ($N_n$), and electric scalar potential ($V$) [4].

\[
\frac{\partial N_e}{\partial t} = S + N_e \alpha \left[ W_e - N_e N_p \beta_{ep} - \nabla \cdot (N_e W_e) \right] + \nabla \cdot (D V N_e)
\]

(1)

\[
\frac{\partial N_p}{\partial t} = S + N_e \alpha \left[ W_p - N_e N_p \beta_{ep} - N_p N_e \beta_{ep} - \nabla \cdot (N_p W_p) \right]
\]

(2)

\[
\frac{\partial N_n}{\partial t} = N_n \eta \left[ W_n - N_n N_p \beta_{ep} - \nabla \cdot (N_n W_n) \right] - \nabla \cdot \left( e(N_p - N_e - N_n) \right)
\]

(3)

where $t$ is the time, $W_e$, $W_p$, and $W_n$ are the electron, positive ion, and negative ion drift velocities, respectively, and $D$ is the electron diffusion coefficient. The symbols $\alpha$, $\eta$, and $\beta$ denote the ionization, attachment, and recombination coefficients, respectively. The term $S$ represents the source term due to photoionization. In the discharge simulation, the material functions are used similarly to those presented in [5]. The discharge current is calculated by the generalized energy approach, which yields reliable results when combined with the FEM [6-8].

The transport equations strongly depend on the convective term. The discretization of convective-dominated transport problems can lead to instabilities in numerical solutions. In case a relatively short gap between electrodes is considered, the dominant carrier with high speed is the electron; the ions then move very slowly. Thus, the electrons mainly cause the numerical instability. The instabilities may be noted as the oscillation or divergence of the field solutions in front of the moving electrons where a steep field gradient is observed. To check the instability, the Peclet number $P_e$ is introduced [9]

\[
P_e = h \left\| \beta \right\| / c
\]

(5)

where $h$ is the local mesh diameter, $\beta$ is the convective velocity vector corresponding to $W_e$, and $c$ denotes the diffusivity. The numerical solution becomes unstable when the Peclet number exceeds two [9]. In our simulation, the elements are generated with the criteria of $P_e < 0.4$.

### 3. Secondary Effects of Streamer Propagation

In the current paper, the secondary effects in insulator materials, such as photoemission and photoionization, on gas discharge, specifically on the streamer development and propagation, are executed based on the two-dimensional axisymmetric FEM algorithm.

To evaluate the amount of electrons emitted from the cathode because of the photoemission mechanism, the photonic sources are integrated over the whole discharge space divided into additional rectangular grids, as shown in Fig. 1. The photoemission effect is given by the following equation from [10]:

\[
N_e^\gamma = \frac{\gamma_e N_e \alpha_c W_{es}}{8\pi^2} \int_0^{2\pi} z e^{z^2} d\theta
\]

(6)

where $N_e^\gamma$ is the electron density emitted from the segment $dA$, $\gamma_e$ is the photoemission coefficient, $N_e$ is the electron density emitted from the volume element $V_i$, $\alpha_c$ is the photoemission coefficient, $W_{es}$ is the electron drift speed on the cathode surface, $\mu$ is the absorption coefficient, and $z$ and $c$ are the geometric displacements, respectively, as illustrated in Fig. 1.

![Fig. 1. Schematic representation for evaluating photoemission from the cathode caused by volume $V_1$. The grids in dotted lines represent the small volumes of photonic sources.](image)

To evaluate directly the magnitude of photoionization only at a certain position of the discharge space, the integration over the whole space of interest should be carried out by the photoionization function presented in [11]. Such process requires much computing time as well as different secondary grids in three dimensions. Thus, the background ionization scheme is adopted in the current study to pursue computational efficiency without loss of simulation accuracy. A background of charged particles is provided in the gap as an effective secondary mechanism for the propagation of the cathode-directed streamer. This mechanism is implemented in the model by a constant value source term.

### 4. Numerical Results

#### 4.1 Verification of numerical setup

To verify our numerical setup, the circular parallel-plane electrodes in Fig. 2(a) are tested. The fine meshes are
distributed along the z-axis, and the cell Peclet number is set to less than 0.4, as shown in Fig. 2(b). The pressure of air is 760 Torr, and the temperature is 300 K. The number of mesh elements and nodes used is 9804 and 5144, respectively. The initial charge distribution is located at 0.003 cm from the cathode and is in the form of a Gaussian distribution:

$$N_0|_{\rho=0} = N_0 \exp \left[ -\frac{(r - r_0)^2}{0.006} - \frac{(z - z_0)^2}{0.006} \right]$$

(7)

where $N_0$ is the initial charge density of $10 \text{ cm}^{-3}$, (i.e., number of electrons and positive ions), and $r_0$ and $z_0$ are the center coordinates of the initial charge distribution.

4.2 Secondary effects on streamer propagation

To investigate the secondary effects on the streamer propagation characteristics, three possible combinations from the two secondary processes (i.e., photoemission and background ionization) are tested. The magnitude of background ionization is set to $10^7 \text{ cm}^{-3}$; the other simulation conditions remain the same. Fig. 4 shows the current profiles when the different secondary effects are applied respectively. When both effects are included, the fastest streamer propagation is observed among them. After several nanoseconds, the streamer is fully developed between the electrodes, and the breakdown phenomena appear in all cases. With the propagation of the cathode-directed streamer, the variations of the electron density and the spatial electric field distribution are presented in Figs. 5 and 6, respectively.

Fig. 3. Current profiles for different voltages applied to electrodes

Fig. 4. Current profiles with the different secondary effects

Fig. 5. Electron density at 2.7 (ns) and 4.6 (ns) including all secondary effects where the discharge channel is formed around the z-axis
4.3 Assessment of secondary effects for simulation parameters

To assess quantitatively the effect of each of the various simulation conditions (e.g., photoemission coefficient, background ionization value, and initial charges) on the streamer propagation characteristic, Taguchi’s DOE method is introduced [14-16].

The photoemission coefficient, background ionization, and number of initial charges (i.e., electron-positive ion pairs) are set as the design parameters, as shown in Table 1. Based on the number of design parameters and the settings considered, a standard orthogonal array L9 is selected for the matrix numerical experiment in Table 2. In this array, the columns are assumed mutually orthogonal, and the three factors, A, B, and C, correspond to the three design parameters with three levels [i.e., photoemission coefficient (A), background ionization (B), and number of initial charges (C) used on discharge simulation]. The performance, \( y_i \), in (8), among the nine combinations of design parameters, is evaluated in terms of the delay time required for reaching a certain current level of 0.1 mA in Table 2. The sensitivity of each design parameter and its performance are represented by the value of SN ratio. For “the smaller the better” case, which resembles the minimization of the performance (i.e., delay time), the SN ratio can be calculated by

\[
\text{SN ratio} = -10\log\left(\frac{1}{n}\sum \frac{1}{y_i^2}\right)
\]  

(8)

where \( n \) denotes the experiment number belonging to the \( i \)th row in Table 2.

Based on the results in Table 2, Analysis of Means (ANOM) and ANOVA [11-13] are performed to estimate the effects of the three design parameters and to determine the relative importance of each one. Fig. 7 shows the overall mean of the SN ratios of all design factor levels for the delay time. To reduce the delay time, ANOM suggests the C3 level (the number of initial charges) is the best choice of control factor, denoted as C here, as it corresponds to the highest average SN ratio. In other words, the larger the initial charges are, the larger the contribution to shortening the delay time to the other factors considered.

### Table 1. L9(3^4) Orthogonal array and design parameters for the first setup

<table>
<thead>
<tr>
<th>Experiments</th>
<th>A</th>
<th>B</th>
<th>C</th>
<th>Time (ns)</th>
<th>MSD (X10^-17)</th>
<th>SN Ratio</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>1</td>
<td>1</td>
<td>1</td>
<td>5.15</td>
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<td>165.76</td>
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<td>4.35</td>
<td>1.89</td>
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where A denotes the photoemission coefficient, B the background ionization, and C the number of initial charges.

### Table 2. SN ratios calculated by nine experiments through the evaluation function (time) and MSD

<table>
<thead>
<tr>
<th>Experiments</th>
<th>A</th>
<th>B</th>
<th>C</th>
<th>Time (ns)</th>
<th>MSD (X10^-17)</th>
<th>SN Ratio</th>
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where Time denotes the specific time to reach 0.1 mA, MSD denotes the mean square deviation, and SN ratio denotes the signal-to-noise ratio that can be calculated by (8).

Fig. 7. Sensitivity of each parameter factor

Fig. 8 presents the relative importance of various design parameters with respect to the delay time through ANOVA, which is strongly analogous to Fourier analysis that provides the amplitude and power of a harmonic. As seen in the result, evidently, the order of importance of the considered design parameters is C, A, and B. Based on these results, the large number of initial electron-positive ion pairs and appropriate photoemission coefficient are of paramount importance in shortening the delay time to reach the second avalanche.
5. Conclusion

The fully coupled FEM combining the particle transport equations with the Poisson’s equation has been presented for accurately predicting the breakdown voltage in air at atmospheric pressure. To avoid numerical instability, the meshes are carefully generated around the streamer channel based on the cell Peclet number. The validity of the proposed method has been proved through the comparison of the predicted and experimental breakdown onset voltages. Moreover, the effects of numerical conditions of the initial charge, photoemission, and background ionization on discharge phenomena are quantitatively assessed through Taguchi’s DOE method.

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References


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